

## 10A Lead Type Super Low Barrier Diode

#### ■ Features

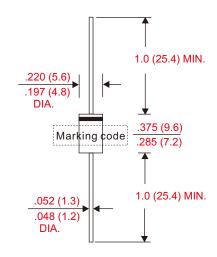
- Axial lead type devices for through hole design.
- · Low forward voltage drop.
- Excellent high temperature stability.
- · Fast switching capability.
- Suffix "G" indicates Halogen-free part, ex.CSRS1045G-A.
- Lead-free parts meet environmental standards of MIL-STD-19500 /228

#### ■ Mechanical data

- Epoxy:UL94-V0 rated flame retardant
- · Case: Molded plastic, DO-201AD / DO-27
- Lead : Axial leads, solderable per MIL-STD-202, Method 208 guranteed
- Polarity : Color band denotes cathode end
- Weight: Approximated 1.10 gram

#### ■ Outline

DO-27(DO-201AD)



Dimensions in inches and (millimeters)

#### ■ Maximum ratings and electrical characteristics

Rating at  $25^{\circ}$ C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Conditions	Symbol	CSRS1045-A			UNIT
Marking code			CSRS1045			
Peak repetitive reverse voltage		V <sub>RRM</sub>				
Working peak reverse voltage		V <sub>RWM</sub>	45			V
DC blocking voltage		V <sub>RM</sub>				
RMS reverse voltage		V <sub>R(RMS)</sub>	32			Α
Forward rectified current		Io	10			Α
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I <sub>FSM</sub>	200			А
Non-repetitive avalanche energy	$T_J = 25^{\circ}C$ , $I_{AS} = 20A$ , $L = 8.5mH$	E <sub>AS</sub>	20			mJ
Thermal resistance	Junction to ambient	$R_{\theta JA}$	54			°C/W
	Junction to case	$R_{\theta JL}$	18			°C/W
Operating and Storage temperature		$T_J, T_{STG}$	-65 ~ +150			°C
Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	UNIT
Reverse breakdown voltage	I <sub>R</sub> = 0.5mA	$V_{(BR)R}$	45			V
Forward voltage drop	$I_F = 8A, T_J = 25^{\circ}C$	V <sub>F</sub>			420	mV
	$I_F = 10A, T_J = 25^{\circ}C$				470	
	$I_F = 10A, T_J = 125^{\circ}C$				410	
Reverse current	$V_R = V_{RRM} T_J = 25^{\circ}C$	I <sub>R</sub>			0.3	mA
	$V_R = V_{RRM} T_J = 100^{\circ}C$				15	
	$V_R = V_{RRM} T_J = 150^{\circ}C$				75	

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## ■ Rating and characteristic curves

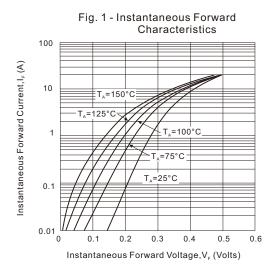
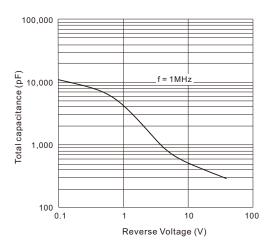


Fig. 2 - Reverse Characteristics

100

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Fig. 3 - Total Capacitance VS. Reverse Voltage



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